





#### **Description**

Transient Voltage Suppressor (TVS) is a circuit protection component that either attenuates (reduces) or filters a transient voltage spike (overvoltage), TVS diodes provide critical protection by going into avalanche breakdown within no more than a few nanoseconds after a strike, clamping the transient voltage, and routing its current to the ground.

#### **Applications**

- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- Power Supply
- Automotive Electronics
- New Energy
- Lightning Protection

#### **Functional Diagram**



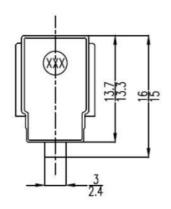
#### **Features**

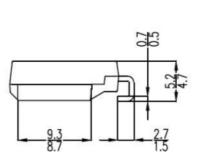
- Chip produced by chemical method
- Junction passivated by high temperature resistant insulating adhesive
- T<sub>J</sub> = 175 °C capability suitable for high reliability and automotive requirement
- Available in Uni-directional polarity only
- Low leakage current
- Low forward voltage drop
- High surge capability
- Meets ISO16750-2 surge specification (varied by test condition)
- LF maximum peak of 245 °C
- AEC-Q101 qualified
- Meets ROHS standards
- Halogen-free
- Package:DO-218AB

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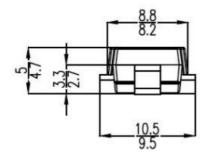
## **SM8SxxA-C Series**

## Package Outline Dimensions (DO-218AB)





**Mounting Pad Layout** 



#### **Maximum Ratings and Characteristics**

(Ratings at 25°C ambient temperature unless otherwise specified.)

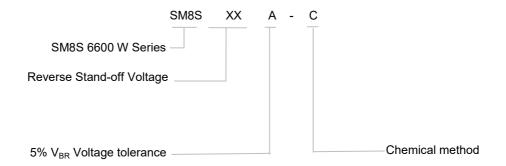
Parameter	Symbol	Value	Unit
Peak pulse power dissipation on 10/1000 μs waveform	P <sub>PPM</sub>	6600	W
Peak pulse power dissipation on 10/10000 μs waveform	P <sub>PPM</sub>	5200	W
Peak Power Dissipation on Infinite Heat Sink at T <sub>C</sub> =50 °C	P <sub>D</sub>	8.0	W
Peak pulse current with 10/1000 µs waveform	I <sub>PPM</sub>	See page 6	А
Operating junction and storage temperature range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to 175	°C

#### Note

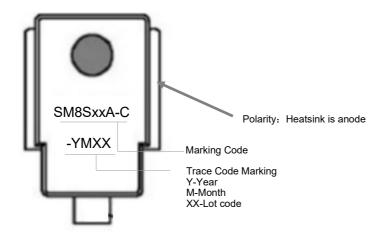
Non-repetitive current pulse derated above TA = 25  $^{\circ}$ C .



## **Part Numbering System**



#### Marking



**Transient Voltage Suppression Diodes** 





#### **Glossary**

Item	Description
V <sub>C</sub>	Clamping Voltage  Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.
V <sub>R</sub>	Reverse Stand-off Voltage Maximum voltage that can be applied to the TVS without operation. NOTE: It is also shown as $V_{\text{WM}}$ (maximum working voltage (maximum d.c. voltage)) and known as rated stand-off voltage ( $V_{\text{so}}$ ).
I <sub>R</sub>	Reverse Leakage Current  Current measured at $V_{R.}$ NOTE : Also shown as $I_{D}$ for stand-by current.
<b>V</b> <sub>BR</sub>	Breakdown Voltage Voltage across TVS at a specified current $I_T$ in the breakdown region.
I <sub>PPM</sub>	Rated Random Recurring Peak Impulse Current  Maximum-rated value of random recurring peak impulse current that may be applied to a device.
P <sub>M(AV)</sub>	Rated Average Power Dissipation  Maximum-rated value of power dissipation resulting from all sources, including transients and standby current, averaged over a short period of time.
P <sub>PPM</sub>	Rated Random Recurring Peak Impulse Power Dissipation  Maximum-rated value of the product of rated random recurring peak impulse current ( $I_{PPM}$ ) multiplies by specified maximum clamping voltage ( $V_{C}$ ).
Сл	Capacitance Capacitance across the TVS measured at a specified frequency and voltage.
<b>V</b> <sub>FS</sub>	Peak Forward Surge Voltage  Peak voltage across an TVS for a specified forward surge current ( $I_{FS}$ ) and time duration.  NOTE: Also shown as $V_{F.}$
I <sub>FS</sub>	Forward Surge Current  Pulsed current through TVS in the forward conducting region.  NOTE : Also shown as I <sub>F.</sub>
α <sub>V(BR)</sub>	Temperature Coefficient of Breakdown Voltage  The change of breakdown voltage divided by the change of temperature.
I <sub>PP</sub>	Peak pulse Current Peak pulse current value applied across the TVS to determine the clamping voltage $V_{\mathbb{C}}$ for a specified wave shape.
<b>I</b> T	Pulsed D.C. Test Current Test current for measurement of the breakdown voltage $V_{BR}$ . This is defined by the manufacturer and usually given in milliamperes with a pulse duration of less than 40 ms.  NOTE: Also shown as $I_{BR}$ .

-(GB-T 18802.321 / IEC 61643-321 / JESD210A)

# **TVS Diodes**

Transient Voltage Suppression Diodes

#### Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted )Table 1

Part Number	Break Volt V <sub>BR</sub> (	age	Test Current I <sub>T</sub>	Reverse Stand-off Voltage	Max. Reverse Leakage I <sub>ℝ</sub> @V <sub>ℝ</sub>		Max. Peak Pulse Current	Max. Clamping Voltage
	Min	Max		<b>V</b> <sub>R</sub>				V <sub>c</sub> @I <sub>PPM</sub>
Uni	(V	<b>'</b> )	(mA)	(V)	(μ <b>A @ 25</b> °C)	(μ <b>A @ 175</b> °C)	(A)	(V)
SM8S10A-C	11.1	12.3	5.0	10.0	10	150	388	17.0
SM8S11A-C	12.2	13.5	5.0	11.0	10	150	363	18.2
SM8S12A-C	13.3	14.7	5.0	12.0	10	150	332	19.9
SM8S13A-C	14.4	15.9	5.0	13.0	10	150	307	21.5
SM8S14A-C	15.6	17.2	5.0	14.0	10	150	284	23.2
SM8S15A-C	16.7	18.5	5.0	15.0	10	150	270	24.4
SM8S16A-C	17.8	19.7	5.0	16.0	10	150	254	26.0
SM8S17A-C	18.9	20.9	5.0	17.0	10	150	239	27.6
SM8S18A-C	20.0	22.1	5.0	18.0	10	150	226	29.2
SM8S20A-C	22.2	24.5	5.0	20.0	10	150	204	32.4
SM8S22A-C	24.4	26.9	5.0	22.0	10	150	186	35.5
SM8S24A-C	26.7	29.5	5.0	24.0	10	150	170	38.9
SM8S26A-C	28.9	31.9	5.0	26.0	10	150	157	42.1
SM8S28A-C	31.1	34.4	5.0	28.0	10	150	145	45.4
SM8S30A-C	33.3	36.8	5.0	30.0	10	150	136	48.4
SM8S33A-C	36.7	40.6	5.0	33.0	10	150	124	53.3
SM8S36A-C	40.0	44.2	5.0	36.0	10	150	114	58.1
SM8S40A-C	44.4	49.1	5.0	40.0	10	150	102	64.5
SM8S43A-C	47.8	52.8	5.0	43.0	10	150	95.1	69.4
SM8S45A-C	50.0	55.3	5.0	45.0	10	150	90.8	72.7
SM8S48A-C	53.3	58.9	5.0	48.0	10	150	85.3	77.4
SM8S51A-C	56.7	62.7	5.0	51.0	10	150	80.1	82.4
SM8S54A-C	60.0	66.3	5.0	54.0	10	150	75.8	87.1
SM8S58A-C	64.4	71.2	5.0	58.0	10	150	70.5	93.6
SM8S60A-C	66.7	73.7	5.0	60.0	10	150	68.2	96.8
SM8S64A-C	71.1	78.6	5.0	64.0	10	150	64.1	103
SM8S70A-C	77.8	86.0	5.0	70.0	10	150	58.4	113
SM8S75A-C	83.3	92.1	5.0	75.0	10	150	54.5	121
SM8S78A-C	86.7	95.8	5.0	78.0	10	150	52.4	126
SM8S85A-C	94.4	104.0	5.0	85.0	10	150	48.2	137

#### Note

<sup>1.</sup> To calculate VBR vs. junction temperature, use the following formula: VBR at T<sub>J</sub> = VBR at 25 °C x (1 + αT x (T<sub>J</sub> - 25)).



#### Performance Curve for Reference(T<sub>A</sub>=25 °C unless otherwise noted)

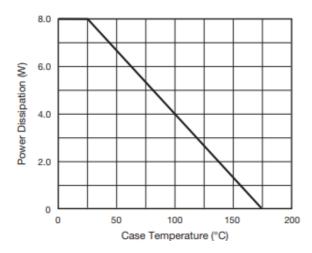


FIGURE 1 Power Derating Curve

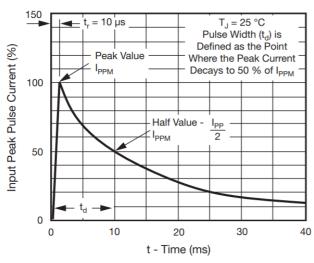


FIGURE 3
Pulse Waveform

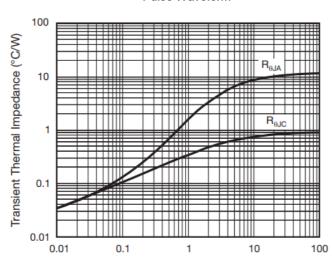


FIGURE 5
Typical Transient Thermal Impedance

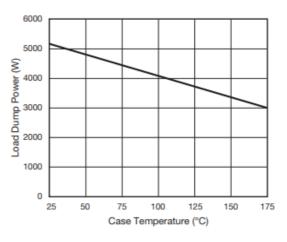


FIGURE 2 Load Dump Power Characteristics (10 ms Exponential Waveform)

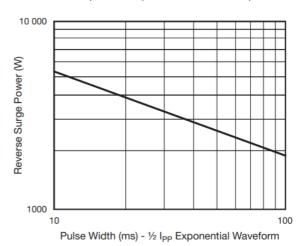
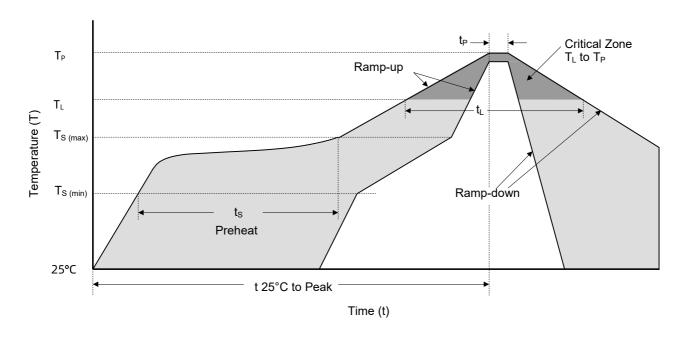


FIGURE 4
Reverse Power Capability

# **Soldering Parameters**



Reflowing Condition

Reflow Solderin	Reflow Soldering Parameters			
	Temperature Min (T <sub>S (min)</sub> )	150 °C		
Pre-heat	Temperature Max (T <sub>S (max)</sub> )	200 °C		
	Time (min to max) (t <sub>s</sub> )	60 ~ 180 seconds		
Average Ramp Up Rate (Li	iquidus Temp (TL) to Peak	3 °C / second max.		
T <sub>s</sub> (max) to T <sub>L</sub>	Ramp-up Rate	3 °C / second max.		
D ()	Temperature (T <sub>L</sub> ) (Liquidus)	217 °C		
Reflow	Time (min to max) (t <sub>L</sub> )	60 ~ 150 seconds		
Peak Tempe	Peak Temperature (T <sub>P</sub> )			
Time of within 5 °C of Actu	ual Peak Temperature (t <sub>P</sub> )	20 ~ 40 seconds		
Ramp-do	own Rate	6 °C / second max.		
Time from 25 °C to	8 Minutes max.			
Do Not	245 °C			

# **Packaging Information**

Таре	Symbol	Dimension			
Tupo	Cymbol	Millimeters	Inches		
	<b>A</b> <sub>0</sub>	10.8 ± 0.3	0.425 ± 0.012		
O <sub>0</sub> P <sub>0</sub> P <sub>2</sub>	B <sub>0</sub>	16.13±0.3	0.635 ± 0.012		
ш о о о о о о о о о о о о о о о о о о о	С	330.0 ± 0.3	13.0 ± 0.012		
	D <sub>0</sub>	1.55 ± 0.2	0.061 ± 0.008		
Ao Pı	D <sub>1</sub>	1.55 ± 0.2	0.061 ± 0.008		
	E	1.75 ± 0.2	0.069 ± 0.008		
	E <sub>1</sub>	13.30 ± 0.2	0.524 ± 0.008		
	F	11.50 ± 0.2	0.453 ± 0.008		
C C	P <sub>0</sub>	4.00 ± 0.2	0.157 ± 0.008		
	P <sub>1</sub>	16.00 ± 0.2	0.630 ± 0.008		
Direction of Feed	P <sub>2</sub>	2.00 ± 0.2	0.079 ± 0.008		
	W	24.00 ± 0.2	0.945 ± 0.008		
	W <sub>1</sub>	25.85 ± 0.2	1.018 ± 0.008		

Part Number	Unit Weight	Package	QTY (Reel)	Packaging Option	Packaging Specification
SM8SxxA-C	2.95 g	DO-218AB	750 PCS	Tape & Reel 13" reel	EIA STD RS-481

SM8SxxA-C Series



#### Usage

- 1.TVS must be operated in the specified ambient temp.
- 2.Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
- 3.Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

#### Replacement

- 1.If TVS is visually damaged, please replace it.
- 2.TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

#### Storage

- 1.Storage Temp. Range: (-55 to 150) °C.
- 2.Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder- ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

#### **Environmental Conditions**

- 1.TVS should not be exposed to the open air, nor direct sunshine.
- 2.TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
- 3.TVS should avoid sand dust, salt mist, or other harmful gases.

#### Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

#### **Installation Mechanical Stress**

- 1.Do not knock TVS when installing, to avoid mechanical damage.
- 2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.

	/	<b>\</b>							_	Page
Package Type	DO-214AA	0	0	ASMB	ASMB-VR			0		
	DO-214AB	0				ASMC	ASMC-VR	ASMD	A5.0SMD	Series
	DO-214AC	ASMA	ASMA-VR					0		ies
_	DO-218AB	0								
Prod	luct Outline (mm)	5.04		5.40		7.94				
<b>V</b> F Reverse	R / Vwm (V) e Stand-off Voltage	5.8 ~ 468	5.0 ~ 440	5.8 ~ 553	5.0 ~ 440	5.8 ~ 512	5.0 ~ 440	5.0 ~ 100	12.0 ~ 170	
( <b>10</b> Rate	PPPM (W) 0/1000 µs) ed Peak ImPulse wer Dissipation	400		60	00	1500 3000 5000			5000	
O Tei	perating mperature (°C)	-55 to +150								

#### **Automotive TVS Diodes (Surface Mount) Feature Overview**

	1	<b>\</b>								Page	
	DO-214AA	0	0	0	0	0	0	0	0		
Package Type	DO-214AB	0							0	Series	
	DO-214AC	0	0				0		0	ies	
_	DO-218AB	SM5SxxA-C	SM5SxxCA-C	SM6SxxA-C	SM6SxxCA-C	SM8SxxA-C	SM8SxxCA-C	SM8TxxA	SM8TxxCA	$\rightarrow$	
Prod	duct Outline (mm)	15.50						1.70	5.00		
<b>V</b> i Revers	R / V <sub>WM</sub> (V) se Stand-off Voltage		10.0 ~ 85.0								
( <b>1</b> 1 Rat Po	P <sub>PPM</sub> (W) 0/1000 µs) ed Peak ImPulse wer Dissipation	36	900	46	4600 6600			8000			
C Te	Operating mperature (°C)	-55 to +175									